Jonathan J S Scragg

List of Publications by Year in descending order

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63 4,678 30 58 papers citations h-index g-index

67 67 67 67 2958

times ranked

citing authors

docs citations

all docs

#	Article	IF	Citations
1	Chalcogenide Perovskites: Tantalizing Prospects, Challenging Materials. Advanced Optical Materials, 2022, 10, .	7.3	58
2	Synthesis of BaZrS ₃ Perovskite Thin Films at a Moderate Temperature on Conductive Substrates. ACS Applied Energy Materials, 2022, 5, 6335-6343.	5.1	27
3	Alkali Dispersion in (Ag,Cu)(In,Ga)Se ₂ Thin Film Solar Cellsâ€"Insight from Theory and Experiment. ACS Applied Materials & Samp; Interfaces, 2021, 13, 7188-7199.	8.0	22
4	Band Tails and Cu–Zn Disorder in Cu ₂ ZnSnS ₄ Solar Cells. ACS Applied Energy Materials, 2020, 3, 7520-7526.	5.1	26
5	Chalcogenide Perovskite BaZrS ₃ : Thin Film Growth by Sputtering and Rapid Thermal Processing. ACS Applied Energy Materials, 2020, 3, 2762-2770.	5.1	59
6	Wideâ€gap (Ag,Cu)(In,Ga)Se ₂ solar cells with different buffer materialsâ€"A path to a better heterojunction. Progress in Photovoltaics: Research and Applications, 2020, 28, 237-250.	8.1	47
7	Prospects for defect engineering in Cu ₂ ZnSnS ₄ solar absorber films. Journal of Materials Chemistry A, 2020, 8, 15864-15874.	10.3	15
8	Thermodynamic stability, phase separation and Ag grading in (Ag,Cu)(In,Ga)Se ₂ solar absorbers. Journal of Materials Chemistry A, 2020, 8, 8740-8751.	10.3	29
9	Back and front contacts in kesterite solar cells: state-of-the-art and open questions. JPhys Energy, 2019, 1, 044005.	5. 3	57
10	Antimonyâ€Doped Tin Oxide as Transparent Back Contact in Cu 2 ZnSnS 4 Thinâ€Film Solar Cells. Physica Status Solidi (A) Applications and Materials Science, 2019, 216, 1900542.	1.8	3
11	Structural and Electronic Properties of Cu ₂ MnSnS ₄ from Experiment and Firstâ€Principles Calculations. Physica Status Solidi (B): Basic Research, 2019, 256, 1800743.	1.5	25
12	Sulfurization of Co-Evaporated Cu(In,Ga)Se ₂ as a Postdeposition Treatment. IEEE Journal of Photovoltaics, 2018, 8, 604-610.	2.5	21
13	The effect of stoichiometry on Cu-Zn ordering kinetics in Cu2ZnSnS4 thin films. Journal of Applied Physics, 2018, 123, .	2.5	35
14	The Single Phase Region in Cu ₂ ZnSnS ₄ Thin Films from Theory and Combinatorial Experiments. Chemistry of Materials, 2018, 30, 4624-4638.	6.7	19
15	TiN Interlayers with Varied Thickness in Cu ₂ ZnSnS(e) ₄ Thin Film Solar Cells: Effect on Na Diffusion, Back Contact Stability, and Performance. Physica Status Solidi (A) Applications and Materials Science, 2018, 215, 1800491.	1.8	13
16	Thio-olivine Mn2SiS4 thin films by reactive magnetron sputtering: Structural and optical properties with insights from first principles calculations. Materials and Design, 2018, 152, 110-118.	7.0	4
17	Investigation of the SnS/Cu ₂ ZnSnS ₄ Interfaces in Kesterite Thin-Film Solar Cells. ACS Energy Letters, 2017, 2, 976-981.	17.4	40
18	In Situ Monitoring of Cu2ZnSnS4 Absorber Formation With Raman Spectroscopy During Mo/Cu2SnS3/ZnS Thin-Film Stack Annealing. IEEE Journal of Photovoltaics, 2017, 7, 906-912.	2.5	6

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19	Evolution of Cu ₂ ZnSnS ₄ during Non-Equilibrium Annealing with Quasi-in Situ Monitoring of Sulfur Partial Pressure. Chemistry of Materials, 2017, 29, 3713-3722.	6.7	40
20	Characterization of TiN back contact interlayers with varied thickness for Cu 2 ZnSn(S,Se) 4 thin film solar cells. Thin Solid Films, 2017, 639, 91-97.	1.8	15
21	Calculation of point defect concentration in Cu2ZnSnS4: Insights into the high-temperature equilibrium and quenching. Journal of Applied Physics, 2017, 122, .	2.5	5
22	Evolution of Na-S(-O) compounds on Cu <inf>2</inf> ZnSnS <inf>4</inf> absorber surface and its effect on CdS growth. , 2016, , .		0
23	Order-disorder transition in B-type Cu2ZnSnS4 and limitations of ordering through thermal treatments. Applied Physics Letters, 2016, 108, .	3.3	46
24	Evolution of Naâ€"S(â€"O) Compounds on the Cu ₂ ZnSnS ₄ Absorber Surface and Their Effects on CdS Thin Film Growth. ACS Applied Materials & Distribution (1988) and State (19	8.0	30
25	Optical properties of reactively sputtered Cu2ZnSnS4 solar absorbers determined by spectroscopic ellipsometry and spectrophotometry. Solar Energy Materials and Solar Cells, 2016, 149, 170-178.	6.2	35
26	Cu–Zn disorder and band gap fluctuations in Cu ₂ ZnSn(S,Se) ₄ : Theoretical and experimental investigations. Physica Status Solidi (B): Basic Research, 2016, 253, 247-254.	1.5	173
27	Reduced interface recombination in Cu2ZnSnS4 solar cells with atomic layer deposition Zn1â°' <i>x</i> Sn <i>x</i> O <i>y</i> buffer layers. Applied Physics Letters, 2015, 107, .	3.3	99
28	Potential of CuS cap to prevent decomposition of Cu ₂ ZnSnS ₄ during annealing. Physica Status Solidi (A) Applications and Materials Science, 2015, 212, 2843-2849.	1.8	11
29	Influence of the Cu ₂ ZnSnS ₄ absorber thickness on thin film solar cells. Physica Status Solidi (A) Applications and Materials Science, 2015, 212, 2889-2896.	1.8	37
30	Raman spectroscopy study on in-situ monitoring of Cu2ZnSnS4 synthesis. , 2015, , .		2
31	Interference effects in photoluminescence spectra of Cu2ZnSnS4 and Cu(In,Ga)Se2 thin films. Journal of Applied Physics, 2015, 118, .	2.5	45
32	Photoluminescence investigation of Cu 2 ZnSnS 4 thin film solar cells. Thin Solid Films, 2015, 582, 146-150.	1.8	19
33	Reactively sputtered films in the Cu x S–ZnS–SnS y system: From metastability to equilibrium. Thin Solid Films, 2015, 582, 208-214.	1.8	17
34	Thin-film Photovoltaics Based on Earth-abundant Materials. RSC Energy and Environment Series, 2014, , 118-185.	0.5	4
35	Rapid annealing of reactively sputtered precursors for Cu ₂ ZnSnS ₄ solar cells. Progress in Photovoltaics: Research and Applications, 2014, 22, 10-17.	8.1	131
36	A low-temperature order-disorder transition in Cu2ZnSnS4 thin films. Applied Physics Letters, 2014, 104, .	3.3	315

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37	Reactive sputtering of Cu2ZnSnS4 thin films $\hat{a}\in$ " Target effects on the deposition process stability. Surface and Coatings Technology, 2014, 240, 281-285.	4.8	6
38	Zn(O, S) Buffer Layers and Thickness Variations of CdS Buffer for Cu \$_{2}\$ZnSnS\$_{4}\$ Solar Cells. IEEE Journal of Photovoltaics, 2014, 4, 465-469.	2.5	82
39	Effects of Back Contact Instability on Cu ₂ ZnSnS ₄ Devices and Processes. Chemistry of Materials, 2013, 25, 3162-3171.	6.7	263
40	Annealing behavior of reactively sputtered precursor films for Cu2ZnSnS4 solar cells. Thin Solid Films, 2013, 535, 22-26.	1.8	43
41	Diffusion of Fe and Na in co-evaporated Cu(In,Ga)Se2 devices on steel substrates. Thin Solid Films, 2013, 535, 188-192.	1.8	13
42	Secondary compound formation revealed by transmission electron microscopy at the Cu2ZnSnS4/Mo interface. Thin Solid Films, 2013, 535, 31-34.	1.8	38
43	Cu out-diffusion in kesteritesâ€"A transmission electron microscopy specimen preparation artifact. Applied Physics Letters, 2013, 102, .	3.3	22
44	A Detrimental Reaction at the Molybdenum Back Contact in Cu ₂ ZnSn(S,Se) ₄ Thin-Film Solar Cells. Journal of the American Chemical Society, 2012, 134, 19330-19333.	13.7	353
45	Reactive sputtering of precursors for Cu2ZnSnS4 thin film solar cells. Thin Solid Films, 2012, 520, 7093-7099.	1.8	55
46	Thermodynamic Aspects of the Synthesis of Thinâ€Film Materials for Solar Cells. ChemPhysChem, 2012, 13, 3035-3046.	2.1	173
47	Influence of precursor sulfur content on film formation and compositional changes in Cu2ZnSnS4 films and solar cells. Solar Energy Materials and Solar Cells, 2012, 98, 110-117.	6.2	172
48	Chemical Insights into the Instability of Cu ₂ ZnSnS ₄ Films during Annealing. Chemistry of Materials, 2011, 23, 4625-4633.	6.7	416
49	The Influences of Sulfurisation Variables and Precursor Composition on the Development of the CZTS Phase., 2011,, 111-153.		0
50	Electrodeposition of Metallic Precursors. , 2011, , 9-57.		1
51	Copper Zinc Tin Sulfide Thin Films for Photovoltaics. , 2011, , .		38
52	Effects of different needles and substrates on CulnS2 deposited by electrostatic spray deposition. Thin Solid Films, 2011, 519, 3544-3551.	1.8	8
53	CulnSe2 precursor films electro-deposited directly onto MoSe2. Journal of Electroanalytical Chemistry, 2010, 645, 16-21.	3.8	8
54	Triple Phase Boundary Photovoltammetry: Resolving Rhodamine B Reactivity in 4â€(3â€Phenylpropyl)â€Pyridine Microdroplets. ChemPhysChem, 2010, 11, 2862-2870.	2.1	11

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55	A 3.2% efficient Kesterite device from electrodeposited stacked elemental layers. Journal of Electroanalytical Chemistry, 2010, 646, 52-59.	3.8	230
56	High Throughput X-ray Diffraction Analysis of Combinatorial Polycrystalline Thin Film Libraries. Analytical Chemistry, 2010, 82, 4564-4569.	6.5	5
57	Synthesis and characterization of Cu2ZnSnS4 absorber layers by an electrodeposition-annealing route. Thin Solid Films, 2009, 517, 2481-2484.	1.8	233
58	Cu ₂ ZnSnSe ₄ thin film solar cells produced by selenisation of magnetron sputtered precursors. Progress in Photovoltaics: Research and Applications, 2009, 17, 315-319.	8.1	276
59	Shallow defects in Cu2ZnSnS4. Physica B: Condensed Matter, 2009, 404, 4949-4952.	2.7	80
60	A review of the challenges facing kesterite based thin film solar cells. , 2009, , .		16
61	Towards Sustainable Photovoltaic Solar Energy Conversion: Studies Of New Absorber Materials. ECS Transactions, 2009, 19, 179-187.	0.5	10
62	New routes to sustainable photovoltaics: evaluation of Cu ₂ ZnSnS ₄ as an alternative absorber material. Physica Status Solidi (B): Basic Research, 2008, 245, 1772-1778.	1.5	322
63	Towards sustainable materials for solar energy conversion: Preparation and photoelectrochemical characterization of Cu2ZnSnS4. Electrochemistry Communications, 2008, 10, 639-642.	4.7	264